Effective-mass theory of collapsed carbon nanotubes

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Band structure is theoretically studied in partially flattened carbon nanotubes within an effective-mass scheme. Effects of inter-wall interactions are shown to be important in non-chiral nanotubes such as zigzag and armchair and can essentially be neglected in chiral nanotubes except in the close vicinity of non-chiral tubes. In fact, inter-wall interactions significantly modify states depending on relative displacement in the flattened region in non-chiral tubes and can convert semiconducting tubes into metallic and vice versa. They diminish rapidly when the chiral angle deviates from that of the zigzag or armchair tube, although the decay is slower in the vicinity of armchair tubes.

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I. INTRODUCTION

Carbon nanotubes were first found in a form of multi-wall cylinders, each of which consists of a rolled graphene sheet.$^{1,2}$ A single-wall nanotube, fabricated later,$^{3,4}$ has a unique electronic property that it changes critically from metallic to semiconducting depending on its tubular circumferential vector. This characteristic feature was first predicted by means of tight-binding models,$^{5–14}$ and was successfully described in an effective-mass approximation.$^{15–17}$ Experimental$^{18–32}$ as well as computational studies$^{33–52}$ have discovered that large diameter nanotubes have an additional stable flattened structure. The purpose of this work is to study electronic structure of collapsed carbon nanotubes for arbitrary chirality within the effective-mass approximation.

The observation of fully collapsed multi-wall carbon nanotubes was reported in transmission electron microscopy,$^{18–25}$ atomic force microscopy,$^{25–28}$ and scanning tunneling microscopy.$^{29–31}$ Multi-wall nanotubes was shown to exhibit structural deformations in FET devices.$^{36}$ Recently, high-yield fabrication of high quality collapsed tubes was reported, using solution-phase extraction of inner tubes from large-diameter multi-wall tubes.$^{32}$

Actually, it is shown theoretically by first-principles energy minimization that both flattened and cylindrical nanotubes are stable or meta-stable and the energy of flattened tube is lower than cylindrical tubes with large diameter.$^{41–45}$ The cylindrical nanotubes collapse into flattened tubes with a barbell-like cross section under hydrostatic pressure or in the presence of injected charge shown by molecular dynamics simulations.$^{36,37}$ Electronic states were studied for collapsed armchair tubes in a tight-binding model$^{18}$ and for collapsed zigzag tubes by density-functional calculations,$^{46,47}$ which demonstrated drastic modification in the energy region close to the Fermi level due to inter-wall interaction.

Transport of crossed nanotube junctions results from interacting individual tubes and has been studied both experimentally,$^{53–57}$ and theoretically.$^{58–61}$ The conductance is found to depend strongly on the crossing angle with large maxima at commensurate stacking of lattices of two nanotubes.$^{58,59}$ A deformation of crossed carbon nanotubes, which may significantly affect the tunneling conductance between nanotubes, has been calculated.$^{77,78}$ Furthermore, a pseudogap has been predicted to appear for an orientationally ordered crystal of nanotubes due to inter-tube transfer.$^{52–65}$

Effects of inter-wall interactions in multi-wall nanotubes were also studied. In general, the lattice structure of each nanotube is commensurate with that of adjacent walls.$^{66,67}$ This makes inter-wall electron hopping negligibly small as a result of the cancellation of inter-wall coupling in the absence of disorder.$^{68–72}$ In fact, inter-wall hopping integrals vary quasi-periodically from site to site and their average over the distance of the order of the circumference vanishes. This property was extensively used for theoretical calculations of excitons in double-wall nanotubes.$^{73,74}$ Further, it is closely related to very weak interlayer interactions in twisted bi- and/or multi-layer graphenes.

Experimentally, each layer of some of epitaxially fabricated graphenes having many layers is known to behave almost as a monolayer.$^{75–85}$ Further, the electronic structure of twisted bilayer graphene with nearly incommensurate lattice structure, both theoretically calculated$^{80,86–96}$ and experimentally observed,$^{81,97–101}$ shows a linear band dispersion near the charge neutrality point, suggesting weak interlayer interaction. On the contrary, the interlayer interaction drastically changes electronic states in displaced bilayer graphene having a commensurate lattice structure.$^{102}$ The end of bilayer graphene can be closed and was observed experimentally after thermal treatment.$^{103}$ Geometry and electronic structure of bilayer graphene with a closed edge were studied by a density functional calculation.$^{104}$

This paper is organized as follows: In Sect. II, an ef-
We have effective potential of inter-wall interaction is derived in an effective-mass scheme. In Sect. III, modification of band structure due to collapse is analyzied by perturbation of inter-wall interaction first for armchair and zigzag nanotube and its dependence on nanotube chirality and stacking in flattened region are discussed based on dominant terms. Numerical results are shown in Sect. IV and a short summary is given in Sect. V.

II. COLLAPSED CARBON NANOTUBES

We consider a nanotube partially flattened as illustrated in Fig. 1 (a). The width of the flattened region is denoted by \( L_F/2 \) and that of the curved region by \( L_C/2 \). We have

\[
L_F + L_C = L,
\]

where \( L \) is the circumference. Figure 1 (b) shows the development map. The tube is usually specified by chiral vector \( \mathbf{L} \), corresponding to the circumference, i.e., \( L = |\mathbf{L}| \). The direction of \( \mathbf{L} \) measured from the horizontal direction is called the chiral angle and denoted by \( \eta \).

In Fig. 1 (b), the right hand side of the line passing through the point \( O \) at \( (\zeta \cos \eta, \zeta \sin \eta) \) and perpendicular to \( \mathbf{L} \) is folded down to form the lower half of the flattened nanotube. The coordinate of the point in the lower side of the flattened region corresponding to point \( \mathbf{r} \) in the upper side will be denoted by \( \mathbf{r} \). Obviously, \( \mathbf{r} \) is given by the mirror reflection with respect to the line perpendicular to \( \mathbf{L} \). In the nanotube, we shall use the coordinates \((x, y)\) fixed onto the tube and therefore we have \( \mathbf{r} = (-x, y) \) for \( \mathbf{r} = (x, y) \). The coordinates of \( \mathbf{r} \) and \( \mathbf{r}' \) in the coordinates \((x', y')\) fixed onto the graphene sheet can be straightforwardly obtained.

Figure 2 (a) shows the lattice structure of graphene, two primitive translation vectors \( \mathbf{a} \) and \( \mathbf{b} \), and three vectors \( \mathbf{\ell}_l \) \((l = 1, 2, 3)\) connecting nearest-neighbor atoms. A unit cell contains two carbon atoms denoted by \( A \) and \( B \).

In a tight-binding model, the wave function is written as

\[
\psi(\mathbf{r}) = \sum_{\mathbf{R}=\mathbf{R}_A} \psi_A(\mathbf{R}) \phi(\mathbf{r} - \mathbf{R}) + \sum_{\mathbf{R}=\mathbf{R}_B} \psi_B(\mathbf{R}) \phi(\mathbf{r} - \mathbf{R}),
\]

where \( \phi(\mathbf{r}) \) denotes a \( \pi \) orbital. The amplitude \( \psi \) at atomic sites \( \mathbf{R} = \mathbf{R}_A \) or \( \mathbf{R}_B \) satisfies

\[
\begin{align*}
\varepsilon \psi_A(\mathbf{R}_A) &= -\gamma_0 \sum_{l=1}^{3} \psi_B(\mathbf{R}_A - \mathbf{\ell}_l) \\
+ \sum_{\mathbf{R}_A} V(\mathbf{R}_A, \mathbf{R}'_A) \psi_A(\mathbf{R}'_A) + \sum_{\mathbf{R}_B} V(\mathbf{R}_A, \mathbf{R}'_B) \psi_A(\mathbf{R}'_B), \\
\varepsilon \psi_B(\mathbf{R}_B) &= -\gamma_0 \sum_{l=1}^{3} \psi_A(\mathbf{R}_B + \mathbf{\ell}_l) \\
+ \sum_{\mathbf{R}_A} V(\mathbf{R}_B, \mathbf{R}'_A) \psi_A(\mathbf{R}'_A) + \sum_{\mathbf{R}_B} V(\mathbf{R}_B, \mathbf{R}'_B) \psi_B(\mathbf{R}'_B),
\end{align*}
\]

where \( \gamma_0 \) is the hopping integral between nearest-neighbor atoms within the wall and inter-wall hopping.
integral $V(\mathbf{R}, \mathbf{R}')$ is nonzero only when carbon atoms at sites $\mathbf{R}$ and $\mathbf{R}'$ are very closely located in the opposite side of the flattened region. Since $\pi$ orbitals are symmetric within the wall, $V(\mathbf{R}, \mathbf{R}')$ is a function of $|\mathbf{R} - \mathbf{R}'|$ well inside the flattened region.

In a monolayer graphene the conduction and valence bands consisting of $\pi$ orbitals cross at K and K' points of the Brillouin zone shown in Fig. 2 (b), where the Fermi level is located.\textsuperscript{105,106} For states in the vicinity of the Fermi level $\varepsilon = 0$, the amplitudes are written as

$$\begin{align*}
\psi_A(\mathbf{R}_A) &= e^{i\mathbf{k} \cdot \mathbf{R}_A} F_A^K(\mathbf{R}_A) + e^{i\mathbf{k}' \cdot \mathbf{R}_A} F_A^{K'}(\mathbf{R}_A), \\
\psi_B(\mathbf{R}_B) &= -\omega e^{i\mathbf{k} \cdot \mathbf{R}_B} F_B^K(\mathbf{R}_B) + e^{i\mathbf{k}' \cdot \mathbf{R}_B} F_B^{K'}(\mathbf{R}_B),
\end{align*}$$

where $\omega = \exp(2\pi i/3).$\textsuperscript{117} Envelope functions $F_A^K, F_A^{K'}, F_B^K, F_B^{K'}$ are assumed to be slowly varying in the scale of the lattice constant. The effective-mass approximation is valid and well reproduces electronic properties as well as the band structure for energy range given by $|\varepsilon| \ll 3\omega$.\textsuperscript{115-117}

In the absence of inter-wall interactions, the envelope functions for the K point satisfy

$$\begin{align*}
\hat{H}^K(\mathbf{k}) \mathbf{F}^K(\mathbf{r}) &= \varepsilon \mathbf{F}^K(\mathbf{r}), \\
\hat{H}^K(\mathbf{k}) &= \gamma \begin{pmatrix} 0 & \hat{k}_+ \\ \hat{k}_- & 0 \end{pmatrix}, \\
\mathbf{F}^K(\mathbf{r}) &= \begin{pmatrix} F_A^K(\mathbf{r}) \\ F_B^K(\mathbf{r}) \end{pmatrix},
\end{align*}$$

where $\hat{k}_\pm = k_x \pm ik_y, k = -i\nabla, \gamma = \sqrt{3}\alpha\gamma_0/2$ is the band parameter with lattice constant $\alpha = 0.246$ nm. Here, wave vector $\mathbf{k}$ is measured from the K point denoted by $\mathbf{K}$. For the K' point, we should exchange $\hat{k}_+$ and $\hat{k}_-$ in the Hamiltonian, i.e.,

$$\begin{align*}
\hat{H}^{K'}(\mathbf{k}) &= \gamma \begin{pmatrix} 0 & \hat{k}_- \\ \hat{k}_+ & 0 \end{pmatrix},
\end{align*}$$

where $\mathbf{k}$ is measured from the K' point, i.e., $\mathbf{K}'$. We shall construct a nanotube in such a way that the hexagon at $\mathbf{L} = n_a \mathbf{a} + n_b \mathbf{b}$ with integers $n_a$ and $n_b$ is rolled onto the origin. For translation $\mathbf{r} \rightarrow \mathbf{r} + \mathbf{L}$, the Bloch function at the K and K' points acquires the phase

$$\begin{align*}
\exp(i\mathbf{K} \cdot \mathbf{L}) &= \exp \left( +\frac{2\pi i \nu}{3} \right), \\
\exp(i\mathbf{K}' \cdot \mathbf{L}) &= \exp \left( -\frac{2\pi i \nu}{3} \right),
\end{align*}$$

where $\nu = 0$ or $\pm 1$, determined by

$$n_a + n_b = 3N + \nu,$$

with integer $N$. Correspondingly, the boundary conditions for $\mathbf{F}(\mathbf{r})$ are given by

$$\begin{align*}
\mathbf{F}^K(\mathbf{r} + \mathbf{L}) &= \exp \left( -\frac{2\pi i \nu}{3} \right) \mathbf{F}^K(\mathbf{r}), \\
\mathbf{F}^{K'}(\mathbf{r} + \mathbf{L}) &= \exp \left( +\frac{2\pi i \nu}{3} \right) \mathbf{F}^{K'}(\mathbf{r}),
\end{align*}$$

Let $\mathbf{T}$ be the primitive lattice translation vector in the axis direction,

$$\mathbf{T} = m_a \mathbf{a} + m_b \mathbf{b},$$

with integers $m_a$ and $m_b$. We have

$$pm_a = n_a - 2n_b, \quad pm_b = 2n_a - n_b,$$

where $p$ is the greatest common divisor of $n_a - 2n_b$ and $2n_a - n_b$. For translation $\mathbf{r} \rightarrow \mathbf{r} + \mathbf{T}$, the Bloch function at the K and K' points acquires the phase

$$\begin{align*}
\exp(i\mathbf{K} \cdot \mathbf{T}) &= \exp \left( +\frac{2\pi i \mu}{3} \right), \\
\exp(i\mathbf{K}' \cdot \mathbf{T}) &= \exp \left( -\frac{2\pi i \mu}{3} \right),
\end{align*}$$

where $\mu = 0$ or $\pm 1$, determined by

$$m_a + m_b = 3M + \mu,$$

with integer $M$. This shows that the K and K' points are mapped onto $k^K_\mu$ and $k^{K'}_\mu$, respectively, with

$$k^K_\mu \equiv +\frac{2\pi \mu}{3T}, \quad k^{K'}_\mu \equiv -\frac{2\pi \mu}{3T},$$

within the one-dimensional first Brillouin zone $[-\pi/T, +\pi/T]$, with $T = |\mathbf{T}|$.

For the K point, the energies and corresponding wave functions are given by\textsuperscript{15-17}

$$\begin{align*}
\varepsilon_{nas}^K(k) &= s \sqrt{k^K_\mu (n)^2 + (k - k^K_\mu)^2}, \\
\mathbf{F}_{nak}^K(\mathbf{r}) &= \frac{1}{\sqrt{AL}} \mathbf{F}_{nak}^K \exp \left[ in^K_\mu (n)x + i(k - k^K_\mu)y \right].
\end{align*}$$
where \( k \) is the wave vector in the axis direction, measured from the center of the one-dimensional Brillouin zone, \( n \) is an integer, \( s = +1 \) and \(-1\) for the conduction and valence band, respectively, and \( A \) is the tube length. For the \( K' \) point, we should replace \( \nu \) with \(-\nu\), with \(-\mu\), and \( b_{\mu\nu}^K(n,k) \) with \( b_{\mu\nu}^{K'}(n,k) = b_{\nu\mu}^K(n,k) \). The band structure is illustrated in Fig. 3 in the vicinity of \( \varepsilon = 0 \).

In the presence of inter-wall coupling, the envelope functions satisfy the Schrödinger equation,

\[
\hat{H}(k) \Psi(r) + \int dr' \Psi(r,r') \hat{F}(r') = \varepsilon \Psi(r),
\]

with

\[
\hat{H}(k) = \begin{pmatrix} \hat{H}_K(k) & 0 \\ 0 & \hat{H}_{K'}(k) \end{pmatrix},
\]

\[
F(r) = \begin{pmatrix} F^K(r) \\ F^{K'}(r) \end{pmatrix}.
\]

The \(4,4\) matrix effective-potential of inter-wall interaction is given by

\[
\tilde{V}(r,r') = V(r) \delta(r' - r),
\]

with

\[
\tilde{V}(r) = \begin{pmatrix} \tilde{V}^{KK}(r) \\ \tilde{V}^{KK'}(r) \\ \tilde{V}^{K'K}(r) \\ \tilde{V}^{K'K'}(r) \end{pmatrix},
\]

where \( \tilde{V}^{KK}(r) \), etc. are \(2,2\) matrices given by

\[
\tilde{V}^{KK}(r) = \begin{pmatrix} V_{AA}(r) & \tilde{V}_{AB}(r) \\ \tilde{V}_{BA}(r) & \tilde{V}_{BB}(r) \end{pmatrix},
\]

etc. Explicit expressions for the effective potential are more easily written down in terms of

\[
\tilde{V}(r) = \begin{pmatrix} V_{AA}(r) & \tilde{V}_{AB}(r) \\ V_{BA}(r) & \tilde{V}_{BB}(r) \end{pmatrix},
\]

where \( \tilde{V}_{AA}(r) \), etc. are \(2,2\) matrices given by

\[
\tilde{V}_{AA}(r) = \begin{pmatrix} \tilde{V}^{KK}(r) & \tilde{V}^{KK'}(r) \\ \tilde{V}^{K'K}(r) & \tilde{V}^{K'K'}(r) \end{pmatrix},
\]

etc. We can obtain \( \tilde{V} \) from \( V(r) \) by a simple unitary transformation.

Then, the effective potential of inter-wall interaction is explicitly given by

\[
\tilde{V}_{AA}(r) = \sum_{R_A} \frac{1}{2} \left[ g(r - R_A) + g(r - R_A') \right] V(R_A, R_A') \times \begin{pmatrix} e^{i \eta r R_A - K_R A} & e^{i \eta r R_A - K_R A} \\ e^{-i \eta r R_A - K_R A} & e^{-i \eta r R_A - K_R A} \end{pmatrix},
\]

\[
\tilde{V}_{AB}(r) = \sum_{R_A} \frac{1}{2} \left[ g(r - R_A) + g(r - R_A') \right] V(R_A, R_B) \times \begin{pmatrix} 0 & e^{i \eta r R_A - K_R B} \\ -e^{-i \eta r R_A - K_R B} & 0 \end{pmatrix},
\]

\[
\tilde{V}_{BB}(r) = \sum_{R_B} \frac{1}{2} \left[ g(r - R_B) + g(r - R_B') \right] V(R_B, R_B) \times \begin{pmatrix} 0 & e^{i \eta r R_B - K_R B} \\ -e^{-i \eta r R_B - K_R B} & 0 \end{pmatrix},
\]

We should note that \( R_A \) and \( R_B \) and also \( K \) and \( K' \) are in the coordinate system \( x'y' \) fixed onto the development map and \( r \) and \( r' \) are in the coordinate system \( xy \) fixed onto carbon nanotubes. Thus, \( r \) and \( r' \) should be converted into the \( x'y' \) system in the above equations.

We have introduced a smoothing function \( g(r) \) which varies smoothly in the range \(|r| \lesssim a \) and decays rapidly and vanishes for \(|r| \gg a \).\footnote{\textsuperscript{19}} It should satisfy the conditions:

\[
\sum_{R_A} g(r - R_A) = \sum_{R_B} g(r - R_B) = 1,
\]

\[
\int dr g(r - R_A) = \int dr g(r - R_B) = \Omega_0,
\]

where \( \Omega_0 \) is the area of a unit cell given by \( \Omega_0 = \sqrt{3} a^2 / 2 \). The function \( g(r - R) \) can be replaced by a delta function when it is multiplied by a function such as \( F(r) \) varying smoothly in the scale of the lattice constant, i.e., \( g(r - R) \approx \Omega_0 \delta(r - R) \).

The effective potential satisfies

\[
\tilde{V}(\bar{r}) = \tilde{V}(r)^T,
\]

and therefore

\[
\tilde{V}(r,r')^T = \tilde{V}(\bar{r}) \delta(r' - \bar{r}) = \tilde{V}(\bar{r'}) \delta(r - \bar{r'}) = \tilde{V}(r', r),
\]

which insures that \( \tilde{V}(r,r') \) is a Hermitian operator. The Hamiltonian should satisfy the time reversal invariance under operation given by\textsuperscript{107,108}

\[
F^T = e^{-i \psi} \begin{pmatrix} 0 & \sigma_z \\ \sigma_z & 0 \end{pmatrix} F^*.
\]
where $\sigma_z$ is the Pauli spin matrix and $\psi$ is an arbitrary phase factor. Thus, the inter-wall potential $\tilde{V}(r)$ should satisfy
\[
\begin{pmatrix}
0 & \sigma_z \\
\sigma_z & 0
\end{pmatrix} \tilde{V}(r) \begin{pmatrix}
0 & \sigma_z \\
\sigma_z & 0
\end{pmatrix} = \tilde{V}(r),
\]
with integers $n$ and $m$. This shows that the inter-wall coupling gives rise to interactions among bands with same $k$ value in the one-dimensional Brillouin zone.

We shall expand the wave functions in terms of those corresponding cylindrical nanotube:
\[
F(r) = \frac{1}{\sqrt{\Lambda L}} \sum_{n,m} \exp[i(k + G_m) y] \\
\times \begin{pmatrix}
\exp[i\kappa_p^K(n) x - ik_p^K y] & 0 \\
0 & \exp[i\kappa_p^{K'}(n) x - ik_p^{K'} y]
\end{pmatrix} F_{nm},
\]
with $G_m = 2\pi m/T$. Then, we have
\[
\hat{H}[n,k+G_m] F_{nm} + \sum_{n',m'} \tilde{V}_{n+n',m-m'} F_{n'm'} = \varepsilon F_{nm},
\]
with
\[
\hat{H}[n,k] = \begin{pmatrix}
\tilde{H}^K_k[\kappa_p^{K'}(n), k - k_p^K] & 0 \\
0 & \tilde{H}^{K'}[\kappa_p^K(n), k - k_p^{K'}]
\end{pmatrix},
\]
and
\[
\tilde{V}_{n+n',m-m'} = \begin{pmatrix}
\tilde{V}^K_{K+K'}(n+n',m-m') & \tilde{V}^{K'}_{K+K'}(n+n',m-m') \\
\tilde{V}^K_{K+K'}(n+n',m-m') & \tilde{V}^{K'}_{K+K'}(n+n',m-m')
\end{pmatrix}.
\]

For actual numerical calculations, the inter-wall hopping integral $V(R_1,R_2)$ is chosen as\cite{58,92,93,109-113}
\[
V(R_1,R_2) = - \left[ \alpha \frac{\gamma_1}{|t|^2} \exp\left(-\frac{|t| - c/2}{\delta}\right) \langle p_1 \cdot t | p_2 \cdot t \rangle - \gamma_0 \exp\left(-\frac{|t| - b}{\delta}\right) \langle p_1 \cdot u | p_2 \cdot u \rangle + \langle p_1 \cdot v | p_2 \cdot v \rangle \right],
\]
where $b$ is the distance between neighboring carbons in graphene, i.e., $b = a/\sqrt{3}$, $c$ the lattice constant along the $a$ axis in graphite given by $c/a = 2.72$, and $\delta$ the decay.

FIG. 3: Schematic illustration of energy bands for (a) an armchair tube $k_\mu \neq 0$, and (b) metallic and (c) semiconducting zigzag nanotubes with $k_\mu = 0$. 

The parameter $\Delta_{\text{edge}}$ in very narrow wires and therefore can safely be neglected.

Extra effective potential localized at edges appears for the flattened region. Actual calculations show that an extra coupling increases from zero to the value well in the flattened region is slowly turned on in the vicinity of its edge.

In order to avoid such unphysical effects, we multiply the inter-wall hopping by a constant $a<z<\frac{a}{2}$ with smoothing length $d$. This $d$ is of the order of lattice constant $a$, but can be regarded as zero in the scale of the effective-mass approximation. In the following, we choose $2\leq d/a \leq 5$, for which the results are independent of this parameter.

As shown by molecular dynamics simulations, coupling in the flattened region is slowly turned on in the vicinity of its edge. When the coupling suddenly appears at a boundary, extra coupling terms may appear, being strongly localized at edges. In order to avoid such unphysical effects, we multiply the inter-wall hopping by the following function:

$$g(r) = \frac{\Omega_0}{\pi d^2} \exp\left(-\frac{r^2}{d^2}\right),$$

with smoothing length $d$. This $d$ is of the order of lattice constant $a$, but can be regarded as zero in the scale of the effective-mass approximation. In the following, we choose $2\leq d/a \leq 5$, for which the results are independent of this parameter.

III. WEAK INTER-WALL COUPLING

A. Inter-Wall Potential in Zigzag and Armchair

Figure 4 shows some examples of the structure of the flattened region in a collapsed zigzag tube ($\eta = 0$). In zigzag tubes, A and B sublattices remain the same, but intra-valley components of inter-wall potential identically vanish, because the K point is mapped onto the K’ point and the K’ point onto the K point by the mirror reflection with respect to a line parallel to the axis. The effective potential in the flattened bilayer region becomes independent of position and is periodic as a function of $\zeta$ with period $a/2$.

We have in general

$$\tilde{V}_{AA} = -\tilde{V}_{BB} = -v_1 \begin{pmatrix} 0 & e^{i\varphi_1} \\ e^{-i\varphi_1} & 0 \end{pmatrix},$$

$$\tilde{V}_{AB} = -\tilde{V}_{BA} = -v_2 \begin{pmatrix} 0 & e^{i\varphi_2} \\ e^{-i\varphi_2} & 0 \end{pmatrix},$$

with real coefficients $v_1$ and $v_2$ and phases $\varphi_1$ and $\varphi_2$ varying with $\zeta$. Actually, difference $\varphi_2 - \varphi_1$ is a relevant parameter changing the band structure, because a relative phase difference between the wave functions associated with the K and K’ point can be chosen arbitrarily and is not important.

For the above potential, the band structure in the bilayer region generally consists of two cone-like bands with crossing points displaced in the wave vector space and have different energies. These two cone-like bands repel each other when they cross. For $\zeta = ja/2$ with $j$ being an integer, in particular, we have a bilayer with AA stacking and $v_1 = \gamma_1, v_2 = 0$, and $e^{i\varphi_1} = \omega^{-j-1}$. In this case, the two cone-like bands have different energies by $\pm \gamma_1$ and do not interact each other. For $\zeta = ja/4$, we have $\varphi_2 = \varphi_1$, for which two cone-like bands displaced from each other both in wave-vector and energy become independent. No AB stacked bilayer is formed.

Figure 5 shows some examples of the structure of the flattened region for armchair tubes ($\eta = \pi/6$). Intervaly components identically vanish, because the K and...
K' points are mapped onto themselves after folding. An A site, however, turns into a B site and a B site turns into an A site, respectively. The effective potential is again independent of the position well inside the flattened region, but varies periodically as a function of $\zeta$ with period $3b/2$, where $b = a/\sqrt{3}$. We can set $\zeta = b(3j + p)/2$, with integer $j$ and $0 \leq p < 3$.

Numerical calculations show

$$V_{AA} = -v_A \begin{pmatrix} 1 & 0 \\ 0 & 0 \end{pmatrix}, \quad V_{BB} = -v_B \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix},$$

$$V_{AB} = V_{BA}^\dagger = iv_{AB} \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix},$$

with real $v_A$, $v_B$, and $v_{AB}$ varying as a function of $\zeta$. For $p = 0$ and 1, we have a bilayer with AB stacking and for $p = 2$, we have a bilayer with AA stacking. In fact, for $p = 0$ we have $v_A = v_{AB} = 0$ and $v_B = \gamma_1$, for $p = 1$ we have $v_A = \gamma_1$ and $v_B = v_{AB} = 0$, and for $p = 2$ we have $v_A = v_B = 0$ and $v_{AB} = -\gamma_1$.

In the following, we shall consider effects of inter-wall interactions in the case of narrow flattened region $L_F/L \ll 1$ by perturbation analysis. This analysis is useful for understanding qualitative features of inter-wall interactions appearing in numerically obtained band structure as shown in the next section.

Because the effective inter-wall potential is independent of position, the spatial part of the matrix element is given by an overlapping integral. For KK elements, for example, we have

$$S_{nn'}^{KK} = \frac{1}{L} \int \left[ \int_{(L+L_F)4/(L-L_F)4} + \int_{(-L+L_F)4}^{(-L-L_F)4} \right] e^{i[k_n(n) + k_{n'}(n')]x} dx,$$

$$= \frac{1}{\pi n + n'} - \frac{2}{3} \sin \left[ \frac{\pi L}{2} \left( n + n' - \frac{2}{3} \nu \right) \right],$$

$$\times \cos \left[ \frac{\pi}{2} \left( n + n' - \frac{2}{3} \nu \right) \right],$$

which for $L_F/L \ll 1$ becomes

$$S_{nn'}^{KK} = \frac{L_F}{L} \cos \left[ \frac{\pi}{2} \left( n + n' - \frac{2}{3} \nu \right) \right].$$

The matrix element $S_{nn'}^{K'K'}$ can be obtained from $S_{nn'}^{KK}$ by replacing $\nu$ with $-\nu$. Further, $S_{nn'}^{KK'}$ and $S_{nn'}^{K'K}$ for different valleys can be obtained by setting $\nu = 0$ in the above.

B. Weak Inter-Wall Coupling: Zigzag Tube

For zigzag tubes, the effective inter-wall potential causes coupling between the K and K' points. In the following, we shall consider the case that the flattened region has the structure of an AA-stacked bilayer, i.e., $\zeta = j(a/2)$ with integer $j$.

In the case of semiconducting tubes ($\nu = \pm 1$), degenerate states associated with the K and K' points are characterized by $s' = s$ and $|\kappa_n(n)| = |\kappa_{-s}(n')|$, giving $n' = -n$ or $\kappa_{-s}(n') = -\kappa_s(n)$, as shown in Fig. 3 (c). The matrix elements are calculated as

$$[V_{KK'}]_{n, n'} = -\gamma_1 \frac{L_F}{L} \nu, \tag{61}$$

independent of $n$. This shows that the two degenerate states split into two by the amount $\pm \gamma_1 L_F/L$ independent of bands. As will be shown in the next section, this can convert the tube into metallic for sufficiently large $L_F/L$.

In metallic case $\nu = 0$, there are two degenerate metallic linear bands for $n = n' = 0$ as shown in Fig. 3 (b). The matrix elements become

$$[V_{KK'}]_{0, 0'} = -\gamma_1 \frac{L_F}{L} \nu = -\gamma_1 \frac{L_F}{2L}, \tag{62}$$

This shows that two degenerate states associated with the K and K' points split into two by the amount $\pm \gamma_1 L_F/(2L)$ independent of bands and there is no band-gap opening.

For parabolic bands $n = \pm n_0$ and $n' = \pm n_0$ with $n_0 > 0$ and $s' = s$, the matrix elements are calculated up to linear order in $k$, and the effective Hamiltonian within
the four degenerate states becomes
\[
\mathcal{H}_{\text{eff}} = -\gamma_1 \frac{L_F}{L} \begin{pmatrix}
+n_0 K & -n_0 K & +n_0 K' & -n_0 K' \\
0 & 0 & i\omega^{j-1} & -\omega^{j-1} \\
i\omega^{j+1} & -\omega^{j+1} & 0 & 0 \\
-\omega^{j+1} & i\omega^{j+1} & 0 & 0
\end{pmatrix},
\]
with \(\delta \approx (1)^n a / \kappa_0 (n_0)\). With the use of the unitary matrix
\[
U = \frac{1}{\sqrt{2}} \begin{pmatrix}
1 & 1 & 0 & 0 \\
0 & 0 & 1 & 1 \\
0 & 0 & -\omega^{j+1} & \omega^{j+1} \\
-\omega^{j+1} & \omega^{j+1} & 0 & 0
\end{pmatrix},
\]
the effective Hamiltonian is converted into
\[
U^\dagger \mathcal{H}_{\text{eff}} U = -\gamma_1 \frac{L_F}{L} \begin{pmatrix}
+1 & 0 & -i\delta & 0 \\
0 & -1 & 0 & +i\delta \\
i\delta & 0 & +1 & 0 \\
0 & -i\delta & 0 & -1
\end{pmatrix}.
\]
This shows that the two bands, each doubly degenerate, are split by the amount \(\pm \gamma_1 L_F / L\) and then the remaining degeneracy is further lifted by \(\delta\) which is proportional to the wave vector and inversely to \(|n|\).

C. Weak Inter-Wall Coupling: Armchair Tube

Armchair nanotubes have \(\nu = 0\) and \(\mu = \pm 1\), and therefore are always metallic in the absence of inter-wall interaction, as shown in Fig. 3 (a). Thus, dominant inter-wall coupling is present only within each of the K and K’ points and \(S_{KK'} = S_{K'K}\). For \(p = 0\) with AB-stacking structure, the matrix elements are calculated as
\[
[V^{KK}]_{ns,ns'} = -\frac{i}{2} \gamma_1 \frac{s'[\kappa_0(n) + i(k - k_\mu)]}{\sqrt{\kappa_0(n)^2 + (k - k_\mu)^2}} - \frac{s[s'(k_\mu)]}{\sqrt{\kappa_0(n)^2 + (k - k_\mu)^2}}\gamma_1 L_F.
\]
For \(n' = -n\) including \(n = 0\), we have \(\kappa_0(n') = -\kappa_0(n)\) and therefore,
\[
[V^{KK}]_{ns,ns'} = -\frac{i}{2} (s + s') \frac{s[s'(k - k_\mu)]}{\sqrt{\kappa_0(n)^2 + (k - k_\mu)^2}} \gamma_1 L_F.
\]
For the metallic linear bands \((n = 0)\), there are two degenerate states \(s = \pm 1\). Off diagonal elements \(s' = -s\) in Eq. (71) vanish, showing that there is no splitting. The bands are shifted by diagonal elements
\[
[V^{KK}]_{ns,ns'} \approx (-1)^n \frac{s[k - k_\mu] \gamma_1 L_F}{\kappa_0(n)} / L.
\]
This corresponds to a parallel shift in the negative \(k\) direction. In contrast, the linear bands at the K' point shift in the positive \(k\) direction.

For parabolic bands \(s' = s\), off-diagonal elements \(n' = -n \neq 0\) in Eq. (71) causes the splitting of \(\pm \gamma_1 L_F / L\) independent of the bands. For small \(k,\) diagonal elements for \(n' = n \neq 0\) become
\[
[V^{KK}]_{ns,ns} \approx (-1)^n \frac{s[k - k_\mu] \gamma_1 L_F}{\kappa_0(n)} / L,
\]
corresponding to a parallel shift in \(k\) direction with amount decreasing with \(|n|\) as \(|n|^{-1}\). Sign of the parallel shift is positive for odd \(n\) and negative for even \(n\).

D. Chiral Tubes: Dominant Terms

It is known that essential properties of carbon nanotubes can be specified by family index \(f\) given by
\[
f = 2n_a - n_b.
\]
For \(L\) having \(f\), we have \(L \cdot a = \frac{1}{2} f a^2\), which means that the chiral vector lies on the line vertical to the horizontal axis with distance \((1/2) f a\) from the origin. From Eq. (74), we have \(n_a + n_b = 3n_a - f\), meaning that the value of \(f\) is determined by \(f\). Therefore, tubes with a given value of \(f\) have the same value of \(n\) and always metallic or semiconducting independent of individual values of \(n_a\) and \(n_b\).
The dominant contribution of effects of inter-wall coupling in the flattened region may be estimated from the Fourier coefficients of small $n$ and $m$.\textsuperscript{91,95} It is natural to choose $n = 0$ for both intra- and inter-valley terms. For intra-valley terms we choose $m = 0$ and for inter-valley terms we choose $m = +\mu$ for $V_{KK}$ and $m = -\mu$ for $V_{K'K'}$.

In the following, in order to show the magnitude of the effective potential, we plot $(L/L_F)\langle V_{n,m}\rangle$, etc. instead of $V_{n,m}$, etc. themselves. Figure 6 shows the average of the absolute value of each element $V$ separately for intra-valley ($KK$ and $K'K'$) and inter-valley elements ($KK'$ and $K'K'$) as a function of the chiral angle $\eta$ for tubes with family number $f = 144$ defined in Eq. (74), i.e., $(n_x,n_y) = (72,0), (73,2), \ldots, (96,48)$. The average of the absolute values of each element of $V$ are shown for $V_{KK}$ and $V_{K'K'}$ by (blue) solid lines and for $V_{KK'}$ and $V_{K'K}$ by (red) dotted lines. The size of the one-dimensional unit cell $T$ is also shown in units of $L$ by (green) dashed lines. We chose relative displacement $\zeta/a = 0, 1/4, \text{and } 1/\sqrt{3} = 0.5774\ldots$ defined in Fig. 1 for three panels and a parameter $\Delta_{\text{edge}}$ is defined in Eq. (55).

In collapsed zigzag tubes with $\eta = 0$, inter-wall interaction is present only between the $K$ and $K'$ points. This corresponds to the fact that phase factors, such as $e^{i(K-R_A-K' R_A)}$ and $e^{i(K R_A-K' R_A)}$ appearing in the off-diagonal elements of $\tilde{V}_{AA}$ given in Eq. (35) and the corresponding terms in $\tilde{V}_{AB}$, etc. in Eqs. (36)-(38), do not cancel out even after summation over $R_A, \text{etc.}$ When $\eta$ slightly deviates from zero, however, these phase factors start to rapidly oscillate in a quasi-periodic manner because they involve $K$ and $K'$ considerably different ($\sim 2\pi/a$) from each other. Thus, the effective inter-wall potential vanishes due to cancellation.

In collapsed armchair tubes with $\eta = \pi/6$, on the other hand, the relevant phase factors involve same $K$ or $K'$. When $\eta$ slightly deviates from $\pi/6$, the phase factors start to oscillate in a quasi-periodic manner but the oscillation is relatively slowly-varying. Thus, the effective potential remains nonzero for small $L_F$ because of incomplete cancellation. Further, it decreases with the deviation of $\eta$ from $\pi/6$ more rapidly for wider flattened region, as shown in Fig. 6.

IV. NUMERICAL RESULTS

For actual calculations, we choose $\gamma_1$ as the energy unit. Further, we choose $n = 0, \pm1, \ldots, \pm n_{\text{max}}$ and for...
FIG. 7: Calculated band structure of collapsed tubes with family index $f = 144$ having zigzag (a), its neighboring structures (b), armchair (f), and its neighboring structures (e) and (d). Parameters are defined in Eqs. (13), (16), and (20), and illustrated in Fig. 1.
Figure 7 shows examples of the band structure in the metallic case with $f = 144$ for $\zeta = 0$. Figures 7 (a) and (b) present those in the vicinity of the zigzag structure, i.e., $(n_a, n_b) = (72, 0)$ and $(73, 2)$ corresponding to $\eta(\pi/6)^{-1} = 0$ and 0.046, respectively. The dominant-term approximation can describe the essential features of the bands near the Fermi level consisting of metallic linear bands, although wave vectors corresponding to zero energy are shifted and the velocity is lowered if we go beyond the dominant-term approximation.

In zigzag nanotubes, the band structure is strongly modified by collapsing due to the strong inter-wall couplings, although the tube remains metallic because of the presence of linear bands at the Fermi level. In fact, the metallic linear bands associated with the K and K’ points are split in energy or shifted in the positive and negative $k$ direction due to the inter-wall coupling as shown in Eq. (62) in the perturbation treatment in the previous section. The excited parabolic bands which are four-fold degenerate are first split into two sets at $k = 0$ and then the remaining degeneracy is lifted by the $k$ linear term as shown in Eq. (65).

With the increase of $\eta$, i.e., when the structure deviates from the zigzag case, effects of inter-wall in-
teration rapidly diminish. In fact, for \((n_a, n_b) = (73, 2)\), shown in Fig. 7 (b), the band structure is modified due to the collapse in such a way that the effective velocity in the axis direction is slightly reduced. This velocity reduction is in qualitative agreement with that observed experimentally \(^{75,80-83,97-100}\) and calculated theoretically \(^{80,86-91}\) in twisted bilayer graphene. With the increase of \(\eta\), however, the band rapidly becomes unaffected by collapsing, although the results are not shown here. For chiral tubes, \(\mu\) takes a nonzero value and therefore the K and K’ points become different in the one-dimensional Brillouin zone as denoted by short vertical dotted lines near zero energy.

Figure 7 also shows results for tubes having a structure close to \(\eta = \pi/6\) (armchair) and for \(\zeta = 0\), i.e., (c) \((n_a, n_b) = (94, 42)\), (d) \((96,44)\), (e) \((95,46)\), and (f) \((96,48)\) corresponding to (c) \(\eta(\pi/6)^{-1} = 0.893\), (d) \(0.930\), (e) \(0.965\), and (f) \(1\). In the armchair tube, the figure shows results only for the K point and those for the K’ point are obtained by mirror reflection with respect to \(k = 0\).

In an armchair tube shown in Fig. 7 (f), the metallic band structure is strongly modified by collapsing and the tube becomes semiconducting due to band-gap opening. In fact, the bottom of the conduction band with \(n = 0\) remains at zero energy, while the top of the valence band with \(n = 0\) is lowered roughly in proportion to \(L_F/L\) due to inter-wall coupling. This is in qualitative agreement with Eq. (67) obtained by the perturbation analysis. For excited parabolic bands, the qualitative features of effects of inter-wall coupling are in agreement with the perturbation analysis giving Eq. (69).
In chiral nanotubes effects of inter-wall interactions are considerably reduced and diminish with the decrease of η from π/6, although their decay is more gradual than in the vicinity of the zigzag tube. This has already been demonstrated in the behavior of the dominant terms shown in Fig. 6. The dominant-term approximation gives quite accurate results near zero energy, but starts to become less valid away from zero energy.

The corresponding results for ζ/α = 1/4 and 1/√3 are shown in Fig. 8. Because the band structure is not affected by displacement ζ in chiral nanotubes, only the results for zigzag and armchair nanotubes are shown. In zigzag and armchair nanotubes, the band structure depends significantly on ζ/α. As shown in Fig. 4, the zigzag tube with η = 0 has the structure of an AA stacked bilayer graphene in the flattened region for ζ/α = 0 and varies as a function of ζ with period α/2. For ζ/α = 1/4, the two layers are displaced from each other in a symmetric way, resulting in the symmetric band structure as shown in Fig. 8 (a). A small band gap appears for LF/L = 1/4, but disappears for sufficiently large LF/L, although explicit results are not shown here.

The displacement ζ/α = 1/√3 = 0.5774⋯ in the zigzag case, shown in Fig. 8 (c), corresponds to the case that the top and bottom layers are slightly displaced from an AA stacked bilayer. This slight displacement results in repulsion between some bands of Fig. 7 (a), giving rise to the band-gap opening. This gap due to symmetry breaking is always present independent of LF/L.
As shown in Fig. 5, for the armchair nanotube, the structure takes the form of AB stacking at $\zeta/a = 0$ and $\zeta/a = 1/(2\sqrt{3}) = 0.2886\ldots$, and then the form of AA stacking at $\zeta/a = 1/\sqrt{3}$. This change repeats itself with period $a/\sqrt{3}$. Thus, in an armchair tube with $\zeta/a = 0.25$, the structure is slightly displaced from the AB stacking. As shown in Fig. 8 (b), this slight displacement results in some distortion of the band structure of Fig. 7 (f) in such a way that the energy becomes asymmetric around the K point. In spite of the asymmetry, the tube remains semiconducting due to nonzero gap.

For $\zeta/a = 1/\sqrt{3}$, the flattened region has the structure of an AA stacked bilayer, and nanotubes become metallic independent of the width of the flattened region, as shown in Fig. 8 (d), because linear bands cross the Fermi level. In agreement with Eq. (72), the metallic linear bands are shifted in the negative $k$ direction. The parabolic bands are split and shifted in different $k$ directions depending on band $n$ qualitatively in agreement with Eq. (73).

In Fig. 9, the dependence on $L_F/L$ is shown for zigzag tubes with $\zeta/a = 0$. With the increase of $L_F/L$, the spectrum gradually takes a form of that of an AA stacked bilayer with appropriately discretized wave-vectors perpendicular to the axis. The tube remains metallic independent of $L_F/L$. The dependence on the width of the flattened region for armchair nanotubes is shown in Fig. 10 for $\zeta/a = 0$. The band structure again gradually approaches that of an AB stacked bilayer. The band gap increases, takes a maximum, and then decreases with

FIG. 11: Calculated band structure of collapsed tubes with $f = 142$ (semiconducting) having (a) zigzag and (b) its neighboring structure, and (c) and (d) near-armchair structure. The zigzag tube turns into metallic from semiconducting due to collapse as in (a).
$L_F/L$, but always remains nonzero.

As some examples for semiconducting nanotubes, we shall consider the case of $f = 142$ corresponding to $(n_a, n_b) = (71, 0), (72, 2), \ldots, (94, 46)$. In this case we always have $\nu = -1$ and $\mu = 0$, i.e., the K and K’ points are both mapped onto the center of the one-dimensional Brillouin zone. Because qualitative feature of the dependence on the chiral angle is the same as in metallic nanotubes, we shall present results in the vicinity of the zigzag and armchair structure in Fig. 11. In fact, inter-wall interactions rapidly become small with the increase of $\eta$ from $\eta = 0$. The same is true for $\eta \sim \pi/6$, i.e., inter-wall effects are most important for $(n_a, n_b) = (94, 46)$ for which $\eta = 0.977 (\pi/6)$ closest to the armchair structure and decrease with the decrease of $\eta$ although more slowly.

One most significant effect of the collapse is to convert semiconducting into metallic in the zigzag tube. This arises due to the splitting of two bands degenerate between the K and K’ points due to inter-wall coupling as has been shown in the perturbation analysis, Eq. (61). All chiral tubes remain semiconducting independent of $L_F/L$, although explicit results are not shown.

V. SUMMARY AND CONCLUSION

We have theoretically studied effects of inter-wall interaction in collapsed carbon nanotubes within an effective-mass scheme. Inter-wall interactions in the flattened region are represented by an effective potential connecting a point on the flattened region to its counter point. Effects of inter-wall interactions are most important in nonchiral nanotubes such as zigzag and armchair. In zigzag and armchair tubes, the band structure varies sensitively with the displacement, corresponding to the sensitive change of the band structure in bilayer graphene. In zigzag nanotubes, in particular, the collapsed tubes become metallic for sufficiently wide flattened region independent of whether the uncollapsed tube is metallic or semiconducting.

In chiral nanotubes, inter-wall interactions can essentially be neglected except in the close vicinity of zigzag and armchair tubes. Inter-wall interactions diminish rapidly when chiral angle deviates from 0 (zigzag) or $\pi/6$ (armchair), although the decay is slower in the vicinity of the armchair tube. In fact, in chiral tubes closest to a zigzag and armchair tube, the semiconducting tube remains semiconducting even for very wide flattened region. Such qualitative features of the chiral angle dependence can be understood through the magnitude of dominant terms corresponding to long-wavelength Fourier coefficients of the effective inter-wall potential.

Small band gap is inversely proportional to diameter in thick chiral semiconducting nanotubes, and is smaller than $\gamma_1 = 0.4$ eV in nonchiral nanotubes, when band gap opens due to inter-layer interaction. Observation of these band gaps is required by means of precise measurement such as infrared transmission spectroscopy and scanning tunneling microscopy. Slightly reduced velocity due to the inter-layer interaction may be observed with scanning tunneling microscopy, angle-resolved photoemission spectroscopy, and Raman spectroscopy in the same way as in twisted bilayer graphene, $^{35,80-83,97-100}$

With the increase in the width of the flattened region, the band structure approaches that of a bilayer ribbon in which the electron motion in the ribbon-width direction is discretized under appropriate boundary conditions. Therefore, the band structure of collapsed nanotubes can be obtained from a bilayer graphene by introducing appropriate boundary conditions corresponding to the curved monolayer region. This problem is left for future study.

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